NSN 5961-01-012-8195

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-012-8195 **Inclosure Material:** Glass **Overall Length:** Between 0.766 inches and 0.792 inches **Overall Diameter:** 0.240 inches **Function For Which Designed:** Voltage variable capacitor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case and mounting hardware **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 1.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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